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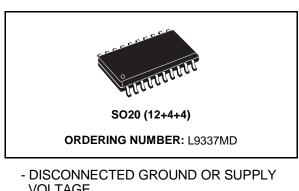
**Distributor of STMicroelectronics: Excellent Integrated System Limited** Datasheet of L9337MD/TR - IC DRIVER TRIPLE LOW SIDE 20SOIC Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



# L9337MD

## TRIPLE LOW SIDE DRIVER

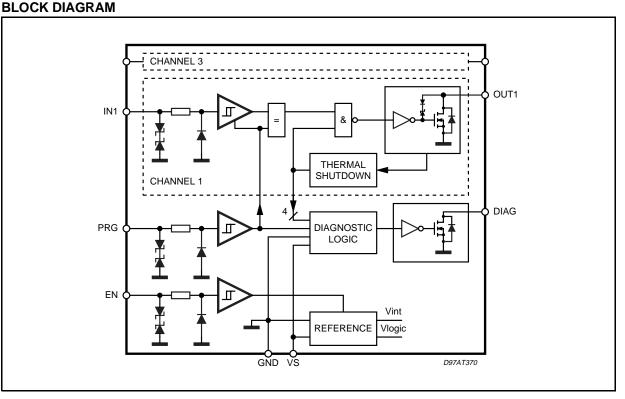
- WIDE INPUT VOLTAGE RANGE FROM -24V UP TO +45V
- WIDE OPERATING SUPPLY VOLTAGE RANGE FROM 4.5V UP TO 32V.
- REVERSE BIASING PROTECTED (V<sub>S</sub> = -24V)
  VERY LOW STANDBY QUIESCENT CUR-
- RENT < 2μA
- PROGRAMMABLE SIGNAL TRANSFER POLARITY
- TTL AND CMOS COMPATIBLE INPUTS
- DEFINED OUTPUT OFF STATE OFF FOR OPEN INPUTS
- THREE OPEN DRAIN DMOS OUTPUTS, WITH R<sub>DSon</sub> = 1.5 Ω at 25°C and V<sub>S</sub> > 6V
- OUTPUT CURRENT LIMITATION
- CONTROLLED OUTPUT SLOPE FOR LOW EMI
- OVERTEMPERATURE SHUT-DOWN
- INTEGRATED OUTPUT CLAMPING FOR FAST INDUCTIVE RECIRCULATION V<sub>FB</sub> > 45V
- STATUS MONITORING FOR
  OVERTEMPERATURE



- VOLTAGE ESD: ALL PINS ARE GUARANTEED TILL 2kV
- ESD: ALL PINS ARE GUARANTEED TILL 2kV HUMAN BODY MODEL

## DESCRIPTION

The L9337MD is a monolithic integrated triple low side driver realized in advanced Multipower-BCD technology. It is intended to drive lines, lamps or relais in automotive or industrial applications.

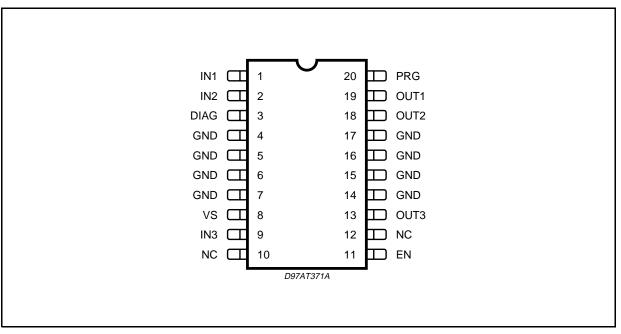




## ABSOLUTE MAXIMUM RATINGS (no damage or latch)

Symbol	Parameter	Value	Unit
Vs	Supply voltage	-24 to 45	V
Pin voltages			
VIN	Input, enable, program	-24 to 45	V
V <sub>OUT</sub>	Output	-0.3 to 45	V
V <sub>DIAG</sub>	Diagnostic output	-0.3 to 45	V

## PIN CONNECTIONS (Top view)



#### **PIN DESCRIPTION**

SO 12+4+4 N₀	Pin Name	Function		
8	VS	SUPPLY VOLTAGE		
4,5,6,7,14, 15,16,17	GND	GROUND		
11	EN	ENABLE		
20	PRG	PROGRAM		
3	DIAG	DIAGNOSTIC		
1	IN1	INPUT 1		
2	IN2	INPUT 2		
9	IN3	INPUT 3		
19	OUT 1	OUTPUT 1		
18	OUT 2	OUTPUT 2		
13	OUT 3	OUTPUT 3		
10, 12	NC	NOT CONNECTED		



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#### L9337MD

#### THERMAL DATA

Symbol	Parameter	<b>SO20</b> (2)	SO(12+4+4) (1)	Unit
R <sub>th (j-pins)</sub>	Thermal resistance junction to pin	_	14 (Тур.)	°C/W
R <sub>th (j-amb)</sub>	Thermal resistance junction to ambient mounted on SMPCB2 board	77 to 97	_	°C/W
T <sub>jMon</sub>	Temperature-monitoring Switch-off-level Switch-on-level		o 190 o 170	°℃ O°

(1) See SGS-THOMSON Microelectronics databook:"Thermal Management in Surface Mount Technology" (2) See SGS-THOMSON Microelectronics databook:"Thermal characteristics of SO20"

**OPERATING CONDITIONS** (The electrical characteristics are valid within the below defined operating ranges, unless otherwise specified. The function will be guaranted by design until  $T_{jMON}$  switch-OFF-level.

Symbol	Parameter	Value	Unit
Vs	Supply Voltage	4.5 to 32	V
VIN	Input pin voltage	-24 to 45	V
V <sub>EN</sub>	Enable pin voltage	-24 to 45	V
Vout, Vd	Output pin voltage	-0.3 to 45	V
Tj	Junction temperature	-40 to 150	°C

#### ELECTRICAL CHARACTERISTICS (Refer to the test circuit, unless otherwise specified.)

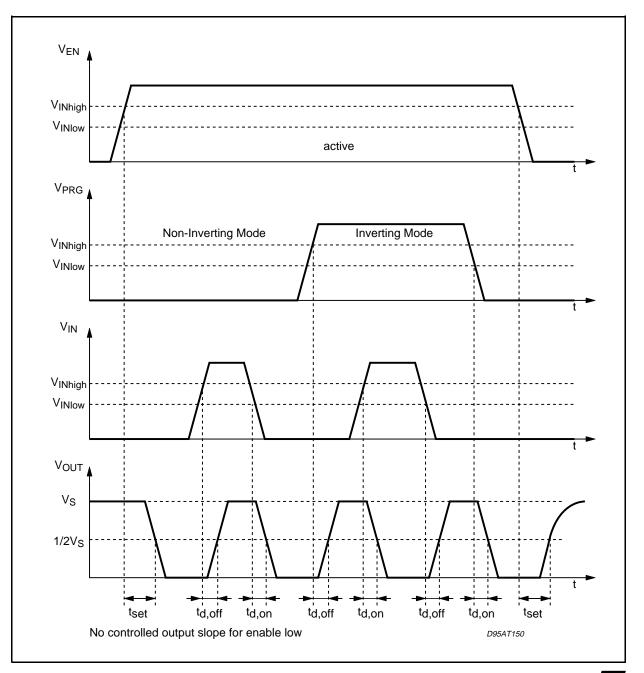
Symbol	Parameter Test Condition		Min.	Тур.	Max.	Unit
ΙQ	$ \begin{array}{ll} \mbox{Quiescent current} & -0.3V \leq V_{EN} \leq 0.5V; \\ V_S = 14V; \ T_j = 85^\circ C \end{array} $			<2	10	μA
		$EN = high; V_S \le 14V$		1.5	2	mA
Inputs IN1	- IN3, PRG					
VINIIow	Input voltage LOW		-24		2.0	V
V <sub>INhigh</sub>	Input voltage HIGH		2.8		45	V
I <sub>IN</sub>	Input current	$-24V \le Vi \le 10V$	-10		15	μΑ
Enable Inp	ut EN					
V <sub>ENIow</sub>	Input voltage LOW		-24		1	V
V <sub>ENhigh</sub>	Input voltage HIGH		3.2		VS	V
R <sub>EN</sub>	Input impedance	-24V < V <sub>i</sub> < 2.5V	10			KΩ
I <sub>EN</sub>	Input current $2.5V \le Vi \le 25V$			20	50	μA
Outputs Ol	UT1-OUT3					
R <sub>DSon</sub> Output ON-resistor to ground		$ \begin{array}{l} V_{S} \geq 6V, \ I_{O} = 0.3A \\ T_{j} = 25^{\circ}C \\ T_{j} = 125^{\circ}C \end{array} $		1.7	2.3 3.5	Ω Ω
I <sub>OLeak</sub>	Leakage current	$V_{O} = V_{S} = 14V; T_{j} = 85^{\circ}C$		≤1	5	μA
V <sub>OClamp</sub>	Output voltage during clamping	time < 200 $\mu$ s; 10mA $\leq$ lo $\leq$ 0.3A	45	52	60	V
losc	Short-circuit current		400	700	1200	mA
Co	Internal output capacities	$V_{O} \ge 4.5V$			100	pF
Diagnostic	output DIAG					
V <sub>Dlow</sub>	Output voltage LOW	I <sub>DL</sub> ≤ 1mA		0.3	0.5	V
I <sub>Dmax</sub>	Max. Output current	Internal current limitation	1	5	15	mA
I <sub>Dleak</sub>	Leakage current	V <sub>S</sub> = 14V; T <sub>J</sub> = 85°C		≤ 0.1	1	μA



#### ELECTRICAL CHARACTERISTICS (Continued)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit	
Timing (see	Timing (see Fig. 1)						
t <sub>d,on</sub>	On delay time	$V_S = 14V, C_{ext} = 0pF$		2.5	3.5	μs	
t <sub>d,off</sub>	Off delay time	$10mA \le I_0 \le 200mA$		3	4.5	μs	
t <sub>set</sub>	Enable settling time				10	μs	
t <sub>d,DIAG</sub>	On or Off diagnostic delay time				10	μs	
Sout	Output slopes		2.5	9	16	V/µs	

### Figure 1







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#### L9337MD

#### **CIRCUIT DESCRIPTION**

The L9337 is a triple low side driver for lines, lamps or inductive loads in automotive and industrial applications.

All INputs are TTL or CMOS compatible. This allows the device to be driven directly by a microcontroller. For the noise immunity, all inputs have a Schmitt-trigger with a hysteresis of typ. 100mV. Each input stage has an input voltage protection from -24V to 10V. The device can be activated with a 'high' signal on ENable input. ENable 'low' switches the device into the sleep mode. In this mode the quiescent current is less than 10 $\mu$ A. A high signal on PRoGramming input changes the signal transfer polarity from noninverting into the inverting mode. Normally this pin is connected to Vs or GND. These pins (PRG and EN) are internally fixed at low status by open input condition. Independent of the PRoGramming input, the OUTput switches off, if the signal INput pin is not connected.

Each output driver has a current limitation of min 0.4A and a seperate thermal shut-down. The thermal shut-down deactivates that output which ex-

ceeds Temperature switch off level. About 20K below this temperature threshold the output will be activated again. This means, that each output is able to sink continuously 285mA without activating thermal shut-down at  $85^{\circ}$ C ambient temperature (SO20). The slew rate of the output is limited to max. 14V/µs to reduce the electromagnetic interference, but not for the enable transfer characteristic (see fig. 1). An integrated active flyback voltage limitation clamps the output voltage during the flyback phase of inductive loads to typ. 50V. The power DMOS switches ON, if the device is enabled and the OUTput swings below ground. This protection avoids the activation of parasitics inside the power DMOS.

The DIAGnostic is an open drain output. The logic status depends on the PRoGramming pin. If the PRG pin is 'low' the DIAG output becomes low, if the device works correctly.

At thermal shut-down of one channel, disconnected ground or supply voltage the DIAGnostic output becomes high. If the PRG pin is 'high' this output is switched off at normal function and switched on at overtemperature.

Pins	EN	PRG	IN	OUT	DIAG
Normal function	Н	L	L	L (on)	L (on)
	Н	L	Н	H (off)	L (on)
	Н	Н	L	H (off)	H(off)
	Н	Н	Н	L (on)	H(off)
	L	Х	Х	H (off)	H(off)
Overtemperature, disconnected ground or supply voltage	Н	L	Х	H (off) *	H (off)
Overtemperature	Н	Н	Х	H (off) *	L (on)

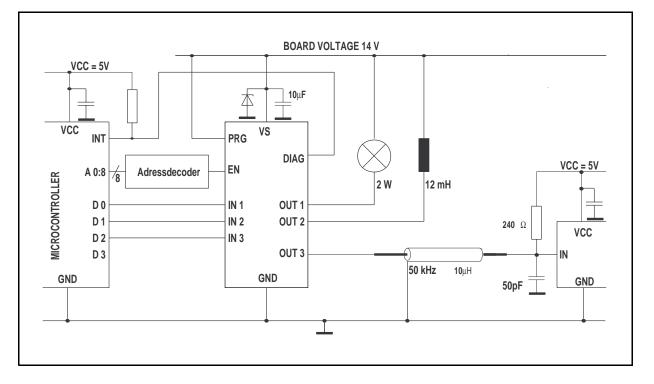
#### DIAGNOSTIC TABLE

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X = not relevant \* selective for each channel at overtemperature

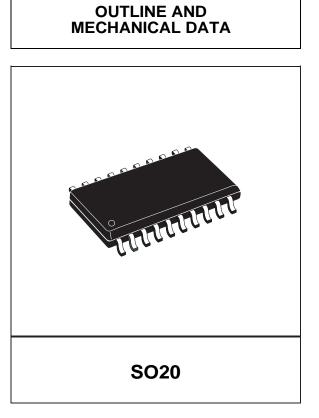


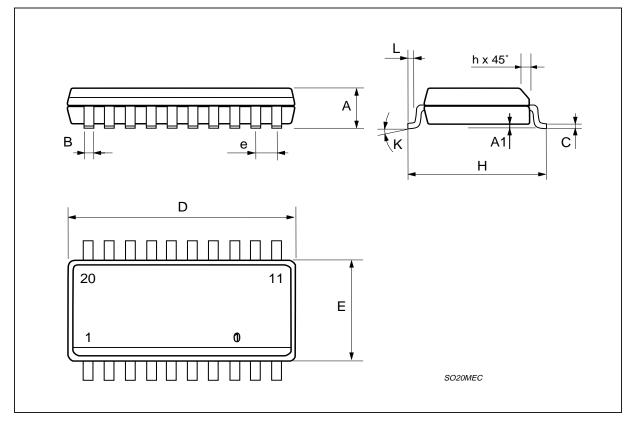
Figure 2: Application circuit for inverting transfer polarity.





DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А	2.35		2.65	0.093		0.104	
A1	0.1		0.3	0.004		0.012	
В	0.33		0.51	0.013		0.020	
с	0.23		0.32	0.009		0.013	
D	12.6		13	0.496		0.512	
E	7.4		7.6	0.291		0.299	
е		1.27			0.050		
н	10		10.65	0.394		0.419	
h	0.25		0.75	0.010		0.030	
L	0.4		1.27	0.016		0.050	
к	0° (min.)8° (max.)						





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